

# **Open Loop Hall Current Sensor CYHCT-FV**

This Hall Effect current sensor is based on open loop principle and designed with a high galvanic isolation between primary conductor and secondary circuit. It can be used for measurement of DC current, DC pulse currents etc. The output of the transducer reflects the real wave of the current carrying conductor.

Product Characteristics	Applications		
<ul> <li>Excellent accuracy</li> <li>Very good linearity</li> <li>Less power consumption</li> <li>Window structure</li> <li>Electrically isolating the output of the transducer from the current carrying conductor</li> <li>No insertion loss</li> <li>Current overload capability</li> </ul>	<ul> <li>Photovoltaic equipment</li> <li>Frequency conversion timing equipment</li> <li>Various power supply</li> <li>Uninterruptible power supplies (UPS)</li> <li>Electric welding machines</li> <li>Transformer substation</li> <li>Numerical controlled machine tools</li> <li>Electric powered locomotive</li> <li>Microcomputer monitoring</li> <li>Electric power network monitoring</li> </ul>		

# **Electrical Data**

Primary Nominal DC Current <i>I</i> <sub>r</sub> (A)	Measuring Range (A)	DC Output Voltage (V)	Window size (mm)	Part number
200	0~±200	x=0: 0-4V ±1.0% x=3: 0-5V ±1.0% x=8: 0-10V ±1.0%		CYHCT-FV-U/B200A-xn
400	0~±400			CYHCT-FV-U/B400A-xn
500	0~±500			CYHCT-FV-U/B500A-xn
600	0~±600		41x14	CYHCT-FV-U/B600A-xn
800	0~±800			CYHCT-FV-U/B800A-xn
1000	0~±1000			CYHCT-FV-U/B1000A-xn
2000	0~±2000			CYHCT-FV-U/B2000A-xn

(n=2, *Vcc*= +12VDC±5%;; n=3, *Vcc* =+15VDC±5%;; n=4, *Vcc* =+24VDC±5%;, U: unidirectional input current; B: bidirectional input current, please give U or B in Part number)

Supply Voltage Output Voltage at  $I_r$ ,  $T_A$ =25°C: Current Consumption Galvanic isolation, 50/60Hz, 1min: Output Impedance: Load resistance:  $V_{cc} = +12V, +15V, +24VDC \pm 5\%$   $V_{out} = 0-4V, 0-5V, 0-10VDC$   $I_c < 25mA$  3kV rms  $R_{out} < 150\Omega$  $10k\Omega$ 

### Accuracy and Dynamic performance data

Accuracy at  $I_r$ ,  $T_A=25^{\circ}$ C, Linearity from 0 to  $I_r$ ,  $T_A=25^{\circ}$ C, Electric Offset Voltage,  $T_A=25^{\circ}$ C, Magnetic Offset Voltage ( $I_r \rightarrow 0$ ) Thermal Drift of Offset Voltage, Response Time at 90% of  $I_P$  (f=1k Hz) Case Material:

Frequency Bandwidth (-3dB),

Markt Schwabener Str. 8 D-85464 Finsing Germany  $X < \pm 1.0\%$  FS  $E_L < \pm 0.5\%$  FS  $V_{oe} < 50$ mV  $V_{om} < \pm 20$ mV  $V_{ot} < \pm 1.0$ mV/°C  $t_r < 1$ ms PBT, heat resistant 100°C flame retardant  $f_b = DC - 20$  kHz

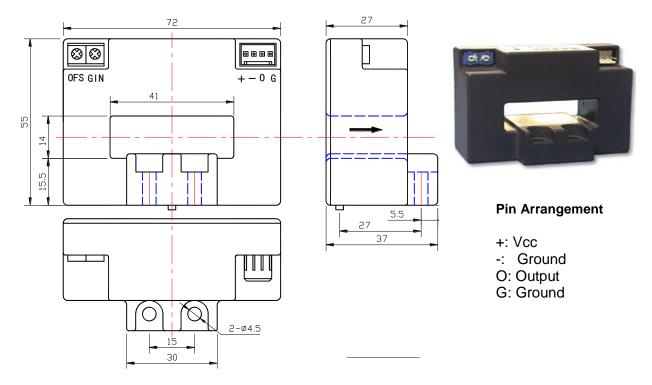
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### **General Data**

Ambient Operating Temperature, Ambient Storage Temperature, Unit weight:  $T_A$  = -25°C ~ +85°C  $T_S$  =-40°C ~ +100°C 217g/unit

## Dimensions



#### Notes:

- 1. Connect the terminals of power source, output respectively and correctly, never make wrong connection.
- 2. Two potentiometers can be adjusted, only if necessary, by turning slowly to the required accuracy with a small screwdriver.
- 3. The best accuracy can be achieved when the window is fully filled with bus-bar (current carrying conductor).
- 4. The in-phase output can be obtained when the direction of current of current carrying conductor is the same as the direction of arrow marked on the transducer